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Electronic Components Sourcing Information

Product Reference Information

Part Number: AD9253TCPZ-125EP
Manufacturer: Analog Devices Inc.
Package: 48-WFQFN Exposed Pad, CSP
Availability: Please confirm with sales

Product Page:

<https://antrexco.com/product/details/analog-devices-inc/ad9253tcpz-125ep.html>

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Note:

This PDF includes an ANTREX product reference cover page.

The original manufacturer datasheet follows from the next page.



AD9253-EP

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REVISION HISTORY

10/12—PrA: Initial Version

SPECIFICATIONS

DC SPECIFICATIONS

AVDD = 1.8 V, DRVDD = 1.8 V, 2 V p-p differential input, 1.0 V internal reference, AIN = -1.0 dBFS, unless otherwise noted.

Table 1.

Parameter ¹	Temp	Min	Typ	Max	Unit
RESOLUTION		14			Bits
ACCURACY					
No Missing Codes	Full	Guaranteed			
Offset Error	Full	-0.8	-0.3	+0.1	% FSR
Offset Matching	Full	-0.6	+0.2	+0.6	% FSR
Gain Error	Full	-12	-3	+2	% FSR
Gain Matching	Full		1.1	1.6	% FSR
Differential Nonlinearity (DNL)	Full	-0.8		+1.9	LSB
	25°C		±0.8		LSB
Integral Nonlinearity (INL)	Full	-4.5		+4.5	LSB
	25°C		±2.0		LSB
TEMPERATURE DRIFT					
Offset Error	Full		±2		ppm/°C
INTERNAL VOLTAGE REFERENCE					
Output Voltage (1 V Mode)	Full	0.98	1.0	1.02	V
Load Regulation at 1.0 mA (V _{REF} = 1 V)	Full		2		mV
Input Resistance	Full		7.5		kΩ
INPUT-REFERRED NOISE					
V _{REF} = 1.0 V	25°C		0.94		LSB rms
ANALOG INPUTS					
Differential Input Voltage (V _{REF} = 1 V)	Full		2		V p-p
Common-Mode Voltage	Full		0.9		V
Differential Input Resistance			5.2		kΩ
Differential Input Capacitance	Full		3.5		pF
POWER SUPPLY					
AVDD	Full	1.7	1.8	1.9	V
DRVDD	Full	1.7	1.8	1.9	V
I _{AVDD} ²	Full		183	205	mA
I _{DRVDD} (ANSI-644 Mode) ²	Full		61	63	mA
I _{DRVDD} (Reduced Range Mode) ²	25°C		53		mA
TOTAL POWER CONSUMPTION					
DC Input	Full		403		mW
Sine Wave Input (Four Channels Including Output Drivers ANSI-644 Mode)	Full		440	480	mW
Sine Wave Input (Four Channels Including Output Drivers Reduced Range Mode)	25°C		425		mW
Power-Down Mode	Full		2		mW
Standby Mode ³	Full		235		mW

¹ See the [AN-835 Application Note](#), *Understanding High Speed ADC Testing and Evaluation*, for definitions and for details on how these tests were completed.

² Measured with a low input frequency, full-scale sine wave on all four channels.

³ It can be controlled via the SPI.

AC SPECIFICATIONS

AVDD = 1.8 V, DRVDD = 1.8 V, 2 V p-p differential input, 1.0 V internal reference, AIN = –1.0 dBFS, unless otherwise noted.

Table 2.

Parameter ¹	Temp	Min	Typ	Max	Unit
SIGNAL-TO-NOISE RATIO (SNR)					
$f_{IN} = 9.7 \text{ MHz}$	25°C		75.3		dBFS
$f_{IN} = 30.5 \text{ MHz}$	25°C		75.2		dBFS
$f_{IN} = 70 \text{ MHz}$	Full	72	74.1		dBFS
$f_{IN} = 140 \text{ MHz}$	25°C		72.2		dBFS
$f_{IN} = 200 \text{ MHz}$	25°C		70.7		dBFS
SIGNAL-TO-NOISE-AND-DISTORTION RATIO (SINAD)					
$f_{IN} = 9.7 \text{ MHz}$	25°C		75.2		dBFS
$f_{IN} = 30.5 \text{ MHz}$	25°C		75.1		dBFS
$f_{IN} = 70 \text{ MHz}$	Full	71.7	74.0		dBFS
$f_{IN} = 140 \text{ MHz}$	25°C		71.9		dBFS
$f_{IN} = 200 \text{ MHz}$	25°C		70.4		dBFS
EFFECTIVE NUMBER OF BITS (ENOB)					
$f_{IN} = 9.7 \text{ MHz}$	25°C		12.2		Bits
$f_{IN} = 30.5 \text{ MHz}$	25°C		12.2		Bits
$f_{IN} = 70 \text{ MHz}$	Full		12.0		Bits
$f_{IN} = 140 \text{ MHz}$	25°C		11.7		Bits
$f_{IN} = 200 \text{ MHz}$	25°C		11.4		Bits
SPURIOUS-FREE DYNAMIC RANGE (SFDR)					
$f_{IN} = 9.7 \text{ MHz}$	25°C		98		dBc
$f_{IN} = 30.5 \text{ MHz}$	25°C		92		dBc
$f_{IN} = 70 \text{ MHz}$	Full	76	90		dBc
$f_{IN} = 140 \text{ MHz}$	25°C		85		dBc
$f_{IN} = 200 \text{ MHz}$	25°C		83		dBc
WORST HARMONIC (SECOND OR THIRD)					
$f_{IN} = 9.7 \text{ MHz}$	25°C		–98		dBc
$f_{IN} = 30.5 \text{ MHz}$	25°C		–92		dBc
$f_{IN} = 70 \text{ MHz}$	Full		–90	–76	dBc
$f_{IN} = 140 \text{ MHz}$	25°C		–85		dBc
$f_{IN} = 200 \text{ MHz}$	25°C		–83		dBc
WORST OTHER HARMONIC (EXCLUDING SECOND OR THIRD)					
$f_{IN} = 9.7 \text{ MHz}$	25°C		–101		dBFS
$f_{IN} = 30.5 \text{ MHz}$	25°C		–100		dBFS
$f_{IN} = 70 \text{ MHz}$	Full		–95	–83	dBFS
$f_{IN} = 140 \text{ MHz}$	25°C		–96		dBFS
$f_{IN} = 200 \text{ MHz}$	25°C		–92		dBFS
TWO-TONE INTERMODULATION DISTORTION (IMD)—AIN1 AND AIN2 = –7.0 dBFS					
$f_{IN1} = 70.5 \text{ MHz}, f_{IN2} = 72.5 \text{ MHz}$	25°C		86		dBc
CROSSTALK ²	Full		–95		dB
CROSSTALK (OVERRANGE CONDITION) ³	25°C		–89		dB
POWER SUPPLY REJECTION RATIO (PSRR) ⁴					
AVDD	25°C		48		dB
DRVDD	25°C		75		dB
ANALOG INPUT BANDWIDTH, FULL POWER	25°C		650		MHz

¹ See the [AN-835 Application Note](#), *Understanding High Speed ADC Testing and Evaluation*, for definitions and for details on how these tests were completed.

² Crosstalk is measured at 70 MHz with an –1.0 dBFS analog input on one channel and no input on the adjacent channel.

³ The overrange condition is specified with 3 dB of the full-scale input range.

⁴ PSRR is measured by injecting a sinusoidal signal at 10 MHz to the power supply pin and measuring the output spur on the FFT. PSRR is calculated as the ratio of the amplitudes of the spur voltage over the pin voltage, expressed in decibels.

DIGITAL SPECIFICATIONS

AVDD = 1.8 V, DRVDD = 1.8 V, 2 V p-p differential input, 1.0 V internal reference, AIN = –1.0 dBFS, unless otherwise noted.

Table 3.

Parameter ¹	Temp	Min	Typ	Max	Unit
CLOCK INPUTS (CLK+, CLK–)					
Logic Compliance		CMOS/LVDS/LVPECL			
Differential Input Voltage ²	Full	0.2		3.6	V p-p
Input Voltage Range	Full	AGND – 0.2		AVDD + 0.2	V
Input Common-Mode Voltage	Full		0.9		V
Input Resistance (Differential)	25°C		15		kΩ
Input Capacitance	25°C		4		pF
LOGIC INPUTS (PDWN, SYNC, SCLK)					
Logic 1 Voltage	Full	1.2		AVDD + 0.2	V
Logic 0 Voltage	Full	0		0.8	V
Input Resistance	25°C		30		kΩ
Input Capacitance	25°C		2		pF
LOGIC INPUT (CSB)					
Logic 1 Voltage	Full	1.2		AVDD + 0.2	V
Logic 0 Voltage	Full	0		0.8	V
Input Resistance	25°C		26		kΩ
Input Capacitance	25°C		2		pF
LOGIC INPUT (SDIO/OLM)					
Logic 1 Voltage	Full	1.2		AVDD + 0.2	V
Logic 0 Voltage	Full	0		0.8	V
Input Resistance	25°C		26		kΩ
Input Capacitance	25°C		5		pF
LOGIC OUTPUT (SDIO/OLM) ³					
Logic 1 Voltage (I _{OH} = 800 μA)	Full		1.79		V
Logic 0 Voltage (I _{OL} = 50 μA)	Full			0.05	V
DIGITAL OUTPUTS (D0±x, D1±x), ANSI-644					
Logic Compliance		LVDS			
Differential Output Voltage (V _{OD})	Full	290	345	400	mV
Output Offset Voltage (V _{OS})	Full	1.15	1.25	1.35	V
Output Coding (Default)		Twos complement			
DIGITAL OUTPUTS (D0±x, D1±x), LOW POWER, REDUCED SIGNAL OPTION					
Logic Compliance		LVDS			
Differential Output Voltage (V _{OD})	Full	160	200	230	mV
Output Offset Voltage (V _{OS})	Full	1.15	1.25	1.35	V
Output Coding (Default)		Twos complement			

¹ See the [AN-835 Application Note](#), *Understanding High Speed ADC Testing and Evaluation*, for definitions and for details on how these tests were completed.

² This is specified for LVDS and LVPECL only.

³ This is specified for 13 SDIO/OLM pins sharing the same connection.

SWITCHING SPECIFICATIONS

AVDD = 1.8 V, DRVDD = 1.8 V, 2 V p-p differential input, 1.0 V internal reference, AIN = -1.0 dBFS, unless otherwise noted.

Table 4.

Parameter ^{1,2}	Temp	Min	Typ	Max	Unit
CLOCK³					
Input Clock Rate	Full	10		1000	MHz
Conversion Rate	Full	10		125	MSPS
Clock Pulse Width High (t_{EH})	Full		4.00		ns
Clock Pulse Width Low (t_{EL})	Full		4.00		ns
OUTPUT PARAMETERS³					
Propagation Delay (t_{PD})	Full		2.3		ns
Rise Time (t_R) (20% to 80%)	Full		300		ps
Fall Time (t_F) (20% to 80%)	Full		300		ps
FCO Propagation Delay (t_{FCO})	Full	1.5	2.3	3.1	ns
DCO Propagation Delay (t_{CPD}) ⁴	Full		$t_{FCO} + (t_{SAMPLE}/16)$		ns
DCO-to-Data Delay (t_{DATA}) ⁴	Full	$(t_{SAMPLE}/16) - 300$	$(t_{SAMPLE}/16)$	$(t_{SAMPLE}/16) + 300$	ps
DCO-to-FCO Delay (t_{FRAME}) ⁴	Full	$(t_{SAMPLE}/16) - 300$	$(t_{SAMPLE}/16)$	$(t_{SAMPLE}/16) + 300$	ps
Lane Delay (t_{LD})			90		ps
Data to Data Skew ($t_{DATA-MAX} - t_{DATA-MIN}$)	Full		± 50	± 200	ps
Wake-Up Time (Standby)	25°C		250		ns
Wake-Up Time (Power-Down) ⁵	25°C		375		μs
Pipeline Latency	Full		16		Clock cycles
APERTURE					
Aperture Delay (t_A)	25°C		1		ns
Aperture Uncertainty (Jitter, t_j)	25°C		135		fs rms
Out-of-Range Recovery Time	25°C		1		Clock cycles

¹ See the [AN-835 Application Note, Understanding High Speed ADC Testing and Evaluation](#), for definitions and for details on how these tests were completed.

² Measured on standard FR-4 material.

³ Can be adjusted via the SPI. The conversion rate is the clock rate after the divider.

⁴ $t_{SAMPLE}/16$ is based on the number of bits in two LVDS data lanes. $t_{SAMPLE} = 1/f_S$.

⁵ Wake-up time is defined as the time required to return to normal operation from power-down mode.

ABSOLUTE MAXIMUM RATINGS

Table 5.

Parameter	Rating
Electrical	
AVDD to AGND	−0.3 V to +2.0 V
DRVDD to AGND	−0.3 V to +2.0 V
Digital Outputs (D0±x, D1±x, DCO+, DCO−, FCO+, FCO−) to AGND	−0.3 V to +2.0 V
CLK+, CLK− to AGND	−0.3 V to +2.0 V
VIN+x, VIN−x to AGND	−0.3 V to +2.0 V
SCLK/DTP, SDIO/OLM, CSB to AGND	−0.3 V to +2.0 V
SYNC, PDWN to AGND	−0.3 V to +2.0 V
RBIAS to AGND	−0.3 V to +2.0 V
VREF, SENSE to AGND	−0.3 V to +2.0 V
Environmental	
Operating Temperature Range (Ambient)	−55°C to +125°C
Maximum Junction Temperature	150°C
Lead Temperature (Soldering, 10 sec)	300°C
Storage Temperature Range (Ambient)	−65°C to +150°C

Stresses above those listed under Absolute Maximum Ratings may cause permanent damage to the device. This is a stress rating only; functional operation of the device at these or any other conditions above those indicated in the operational section of this specification is not implied. Exposure to absolute maximum rating conditions for extended periods may affect device reliability.

THERMAL RESISTANCE

Table 6.

Package Type	Air Flow Velocity (m/sec)	θ_{JA} ¹	Ψ_{JT}	Ψ_{JB}	θ_{JC} TOP	θ_{JC} BOTTOM	Unit
48-Lead LFCSP	0.0	20.3	0.10	5.9	6.1	1.0	°C/W
	1.0	17.6	0.16	N/A ²	N/A ²	N/A ²	°C/W
	2.5	16.5	0.20	N/A ²	N/A ²	N/A ²	°C/W

¹ θ_{JA} for a 4-layer printed circuit board (PCB) with solid ground plane (simulated). Exposed pad soldered to PCB.

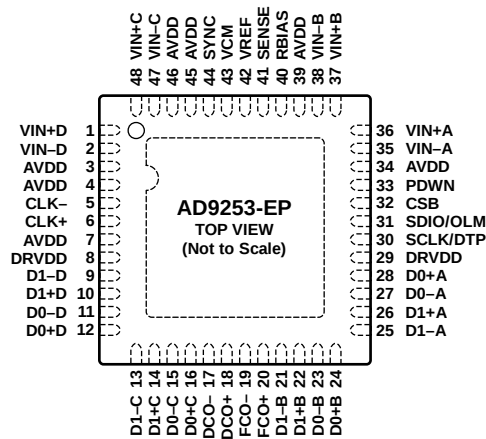
² N/A = not applicable.

ESD CAUTION



ESD (electrostatic discharge) sensitive device. Charged devices and circuit boards can discharge without detection. Although this product features patented or proprietary protection circuitry, damage may occur on devices subjected to high energy ESD. Therefore, proper ESD precautions should be taken to avoid performance degradation or loss of functionality.

PIN CONFIGURATION AND FUNCTION DESCRIPTIONS



NOTES

1. THE EXPOSED THERMAL PAD ON THE BOTTOM OF THE PACKAGE PROVIDES THE ANALOG GROUND FOR THE PART. THIS EXPOSED PAD MUST BE CONNECTED TO GROUND FOR PROPER OPERATION.

10065-007

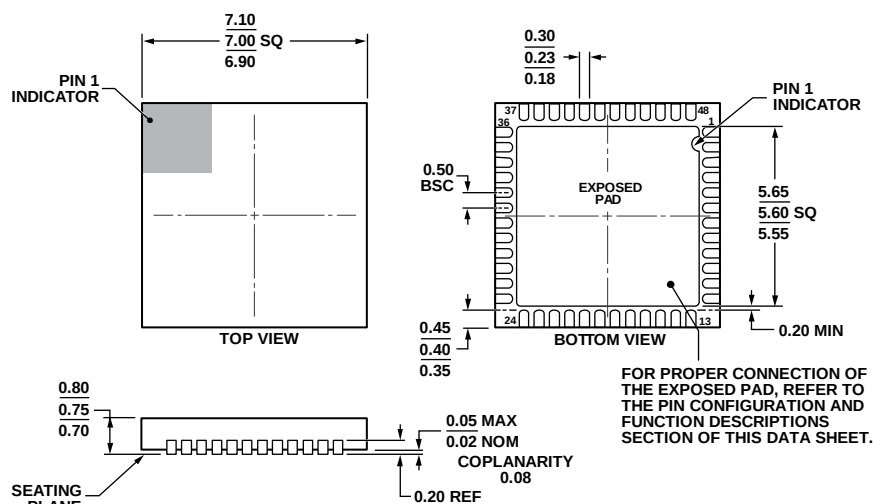
Figure 2. Pin Configuration, Top View

Table 7. Pin Function Descriptions

Pin No.	Mnemonic	Description
0	AGND, Exposed Pad	Analog Ground, Exposed Pad. The exposed thermal pad on the bottom of the package provides the analog ground for the part. This exposed pad must be connected to ground for proper operation.
1	VIN+D	ADC D Analog Input True.
2	VIN-D	ADC D Analog Input Complement.
3, 4, 7, 34, 39, 45, 46	AVDD	1.8 V Analog Supply Pins.
5, 6	CLK-, CLK+	Differential Encode Clock. PECL, LVDS, or 1.8 V CMOS inputs.
8, 29	DRVDD	Digital Output Driver Supply.
9	D1-D	Channel D Digital Output 1 Complement.
10	D1+D	Channel D Digital Output 1 True.
11	D0-D	Channel D Digital Output 0 Complement.
12	D0+D	Channel D Digital Output 0 True.
13	D1-C	Channel C Digital Output 1 Complement.
14	D1+C	Channel C Digital Output 1 True.
15	D0-C	Channel C Digital Output 0 Complement.
16	D0+C	Channel C Digital Output 0 True.
17	DCO-	Data Clock Output Complement.
18	DCO+	Data Clock Output True.
19	FCO-	Frame Clock Output Complement.
20	FCO+	Frame Clock Output True.
21	D1-B	Channel B Digital Output 1 Complement.
22	D1+B	Channel B Digital Output 1 True.
23	D0-B	Channel B Digital Output 0 Complement.
24	D0+B	Channel B Digital Output 0 True.
25	D1-A	Channel A Digital Output 1 Complement.
26	D1+A	Channel A Digital Output 1 True.
27	D0-A	Channel A Digital Output 0 Complement.
28	D0+A	Channel A Digital Output 0 True.

Pin No.	Mnemonic	Description
30	SCLK/DTP	SPI Clock Input/Digital Test Pattern.
31	SDIO/OLM	SPI Data Input and Output Bidirectional SPI Data/Output Lane Mode.
32	CSB	SPI Chip Select Bar. Active low enable; 30 k Ω internal pull-up.
33	PDWN	Digital Input, 30 k Ω Internal Pull-Down. PDWN high = power-down device. PDWN low = run device, normal operation.
35	VIN–A	ADC A Analog Input Complement.
36	VIN+A	ADC A Analog Input True.
37	VIN+B	ADC B Analog Input True.
38	VIN–B	ADC B Analog Input Complement.
40	RBIAS	Sets Analog Current Bias. Connect to 10 k Ω (1% tolerance) resistor to ground.
41	SENSE	Reference Mode Selection.
42	VREF	Voltage Reference Input and Output.
43	VCM	Analog Input Common-Mode Voltage.
44	SYNC	Digital Input. SYNC input to clock divider.
47	VIN–C	ADC C Analog Input Complement.
48	VIN+C	ADC C Analog Input True.

OUTLINE DIMENSIONS



COMPLIANT TO JEDEC STANDARDS MO-220-WKKD.

Figure 3. 48-Lead Lead Frame Chip Scale Package [LFCSP_WQ]
 7 mm × 7 mm Body, Very Very Thin Quad
 (CP-48-13)
 Dimensions shown in millimeters

ORDERING GUIDE

Model ¹	Temperature Range	Package Description	Package Option
AD9253-TCPZ-125EP	–55°C to +125°C	48-Lead Lead Frame Chip Scale Package [LFCSP_WQ]	CP-48-13
AD9253-TCPZR7-125EP	–55°C to +125°C	48-Lead Lead Frame Chip Scale Package [LFCSP_WQ]	CP-48-13

¹ Z = RoHS Compliant Part.

NOTES

NOTES